DATA SHEET

PCD8544

48 × 84 pixels matrix LCD controller/driver

Product specification

File under Integrated Circuits, IC17

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Philips Semiconductors

PHILIPS

CONTENTS

48 × 84 pixels matrix LCD controller/driver PCD8544

1 FEATURES

- Single chip LCD controller/driver
- 48 row, 84 column outputs
- Display data RAM 48 × 84 bits
- On-chip:
  - Generation of LCD supply voltage (external supply also possible)
  - Generation of intermediate LCD bias voltages
  - Oscillator requires no external components (external clock also possible).
- External $\overline{RES}$ (reset) input pin
- Serial interface maximum 4.0 Mbits/s
- CMOS compatible inputs
- Mux rate: 48
- Logic supply voltage range V_{DD} to V_{SS}: 2.7 to 3.3 V
- Display supply voltage range V_{LCD} to V_{SS}
  - 6.0 to 8.5 V with LCD voltage internally generated (voltage generator enabled)
  - 6.0 to 9.0 V with LCD voltage externally supplied (voltage generator switched-off).
- Low power consumption, suitable for battery operated systems
- Temperature compensation of V_{LCD}
- Temperature range: −25 to +70 °C.

2 GENERAL DESCRIPTION

The PCD8544 is a low power CMOS LCD controller/driver, designed to drive a graphic display of 48 rows and 84 columns. All necessary functions for the display are provided in a single chip, including on-chip generation of LCD supply and bias voltages, resulting in a minimum of external components and low power consumption.

The PCD8544 interfaces to microcontrollers through a serial bus interface.

The PCD8544 is manufactured in n-well CMOS technology.

3 APPLICATIONS

- Telecommunications equipment.

4 ORDERING INFORMATION

TYPE NUMBER	PACKAGE		
	NAME	DESCRIPTION	VERSION
PCD8544U	–	chip with bumps in tray; 168 bonding pads + 4 dummy pads	–

5 BLOCK DIAGRAM

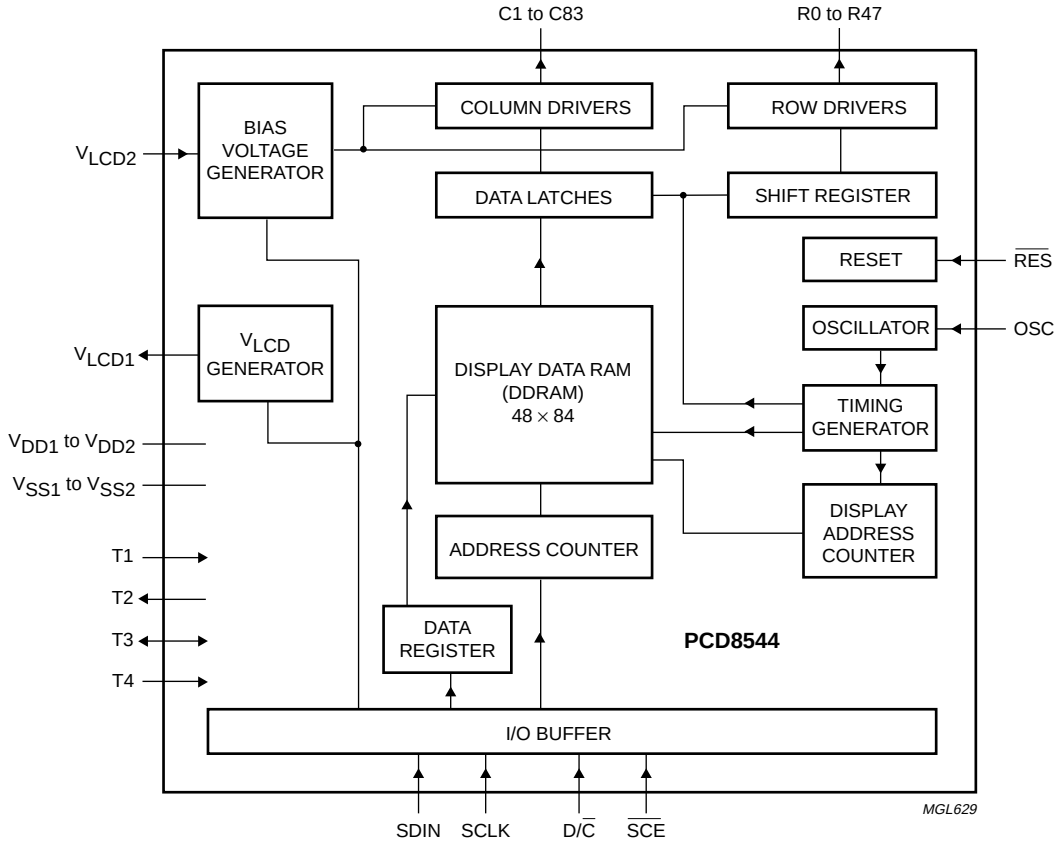


Fig.1 Block diagram.

6 PINNING

SYMBOL	DESCRIPTION
R0 to R47	LCD row driver outputs
C0 to C83	LCD column driver outputs
V_{SS1}, V_{SS2}	ground
V_{DD1}, V_{DD2}	supply voltage
V_{LCD1}, V_{LCD2}	LCD supply voltage
T1	test 1 input
T2	test 2 output
T3	test 3 input/output
T4	test 4 input
SDIN	serial data input
SCLK	serial clock input
D/$\overline{C}$	data/$\overline{command}$
$\overline{SCE}$	chip enable
OSC	oscillator
$\overline{RES}$	external reset input
dummy1, 2, 3, 4	not connected

Note

1. For further details, see Fig.18 and Table 7.

6.1 Pin functions

6.1.1 R0 TO R47 ROW DRIVER OUTPUTS

These pads output the row signals.

6.1.2 C0 TO C83 COLUMN DRIVER OUTPUTS

These pads output the column signals.

6.1.3 V_{SS1}, V_{SS2}: NEGATIVE POWER SUPPLY RAILS

Supply rails V_{SS1} and V_{SS2} must be connected together.

6.1.4 V_{DD1}, V_{DD2}: POSITIVE POWER SUPPLY RAILS

Supply rails V_{DD1} and V_{DD2} must be connected together.

6.1.5 V_{LCD1}, V_{LCD2}: LCD POWER SUPPLY

Positive power supply for the liquid crystal display. Supply rails V_{LCD1} and V_{LCD2} must be connected together.

6.1.6 T1, T2, T3 AND T4: TEST PADS

T1, T3 and T4 must be connected to V_{SS}, T2 is to be left open. Not accessible to user.

6.1.7 SDIN: SERIAL DATA LINE

Input for the data line.

6.1.8 SCLK: SERIAL CLOCK LINE

Input for the clock signal: 0.0 to 4.0 Mbits/s.

6.1.9 D/$\overline{C}$: MODE SELECT

Input to select either command/address or data input.

6.1.10 $\overline{SCE}$: CHIP ENABLE

The enable pin allows data to be clocked in. The signal is active LOW.

6.1.11 OSC: OSCILLATOR

When the on-chip oscillator is used, this input must be connected to V_{DD}. An external clock signal, if used, is connected to this input. If the oscillator and external clock are both inhibited by connecting the OSC pin to V_{SS}, the display is not clocked and may be left in a DC state. To avoid this, the chip should always be put into Power-down mode before stopping the clock.

6.1.12 $\overline{RES}$: RESET

This signal will reset the device and must be applied to properly initialize the chip. The signal is active LOW.

7 FUNCTIONAL DESCRIPTION

7.1 Oscillator

The on-chip oscillator provides the clock signal for the display system. No external components are required and the OSC input must be connected to V_{DD}. An external clock signal, if used, is connected to this input.

7.2 Address Counter (AC)

The address counter assigns addresses to the display data RAM for writing. The X-address X_6 to X_0 and the Y-address Y_2 to Y_0 are set separately. After a write operation, the address counter is automatically incremented by 1, according to the V flag.

7.3 Display Data RAM (DDRAM)

The DDRAM is a 48 × 84 bit static RAM which stores the display data. The RAM is divided into six banks of 84 bytes (6 × 8 × 84 bits). During RAM access, data is transferred to the RAM through the serial interface. There is a direct correspondence between the X-address and the column output number.

7.4 Timing generator

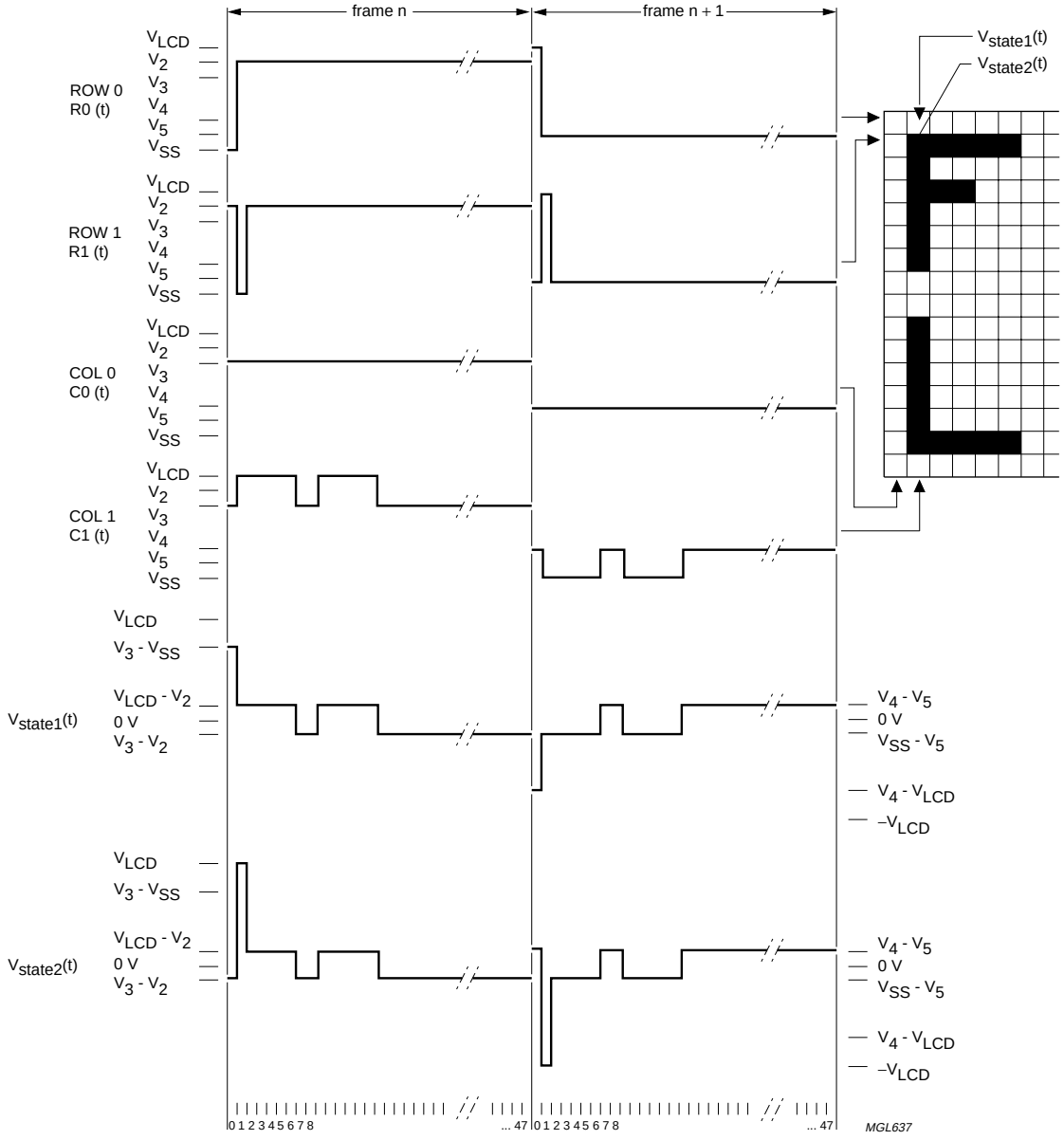
The timing generator produces the various signals required to drive the internal circuits. Internal chip operation is not affected by operations on the data buses.

7.5 Display address counter

The display is generated by continuously shifting rows of RAM data to the dot matrix LCD through the column outputs. The display status (all dots on/off and normal/inverse video) is set by bits E and D in the ‘display control’ command.

7.6 LCD row and column drivers

The PCD8544 contains 48 row and 84 column drivers, which connect the appropriate LCD bias voltages in sequence to the display in accordance with the data to be displayed. Figure 2 shows typical waveforms. Unused outputs should be left unconnected.



$V_{state1}(t) = C1(t) - R0(t)$.
$V_{state2}(t) = C1(t) - R1(t)$.

Fig.2 Typical LCD driver waveforms.

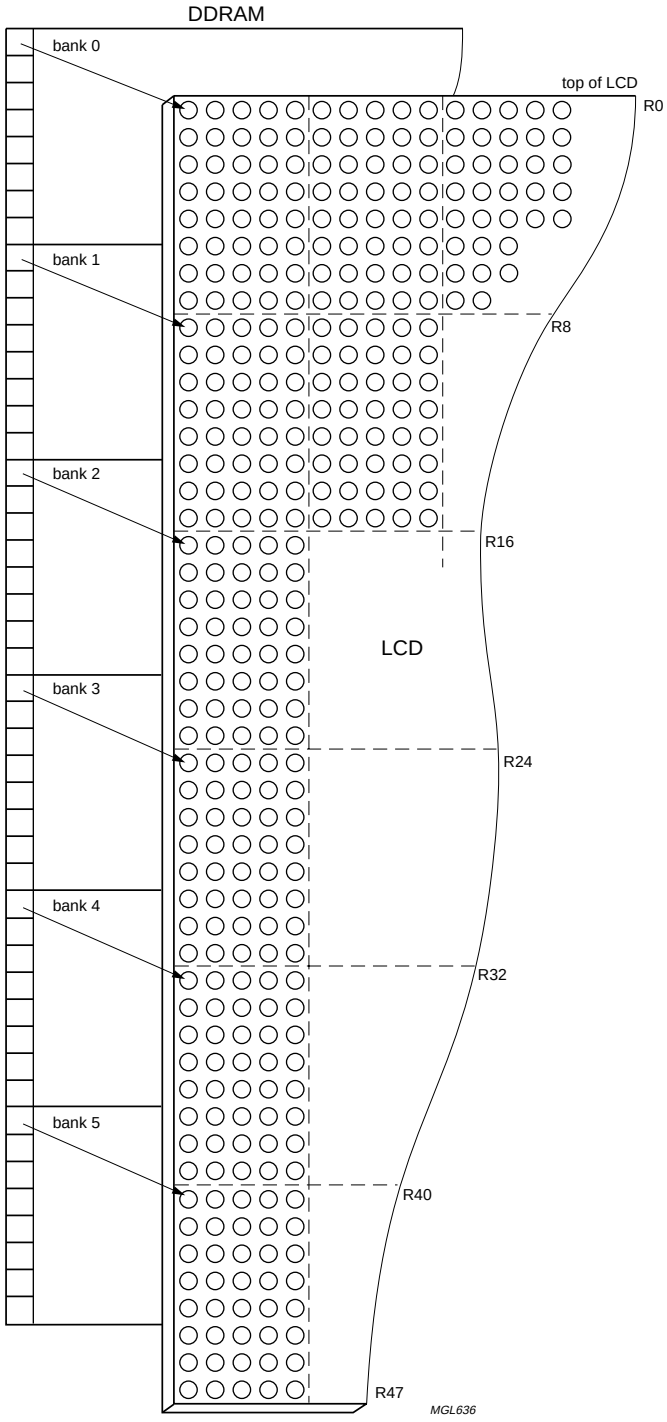


Fig.3 DDRAM to display mapping.

7.7 Addressing

Data is downloaded in bytes into the 48 by 84 bits RAM data display matrix of PCD8544, as indicated in Figs. 3, 4, 5 and 6. The columns are addressed by the address pointer. The address ranges are: X 0 to 83 (1010011), Y 0 to 5 (101). Addresses outside these ranges are not allowed. In the vertical addressing mode (V = 1), the Y address increments after each byte (see Fig.5). After the last Y address (Y = 5), Y wraps around to 0 and X increments to address the next column. In the horizontal addressing mode (V = 0), the X address increments after each byte (see Fig.6). After the last X address (X = 83), X wraps around to 0 and Y increments to address the next row. After the very last address (X = 83 and Y = 5), the address pointers wrap around to address (X = 0 and Y = 0).

7.7.1 DATA STRUCTURE

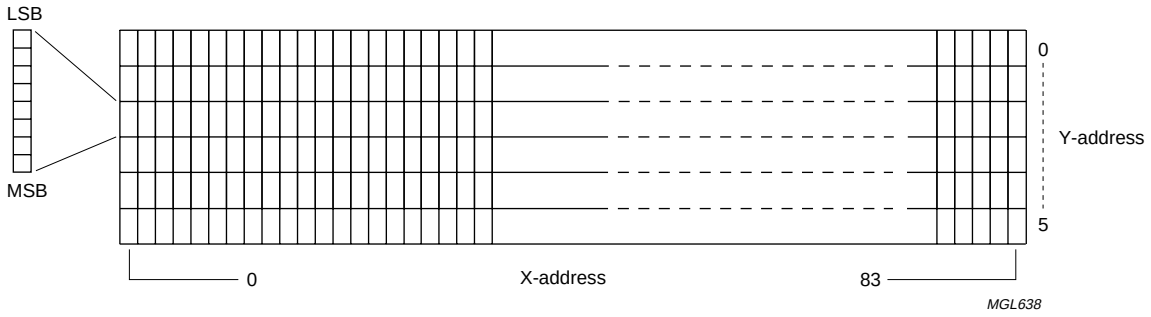


Fig.4 RAM format, addressing.

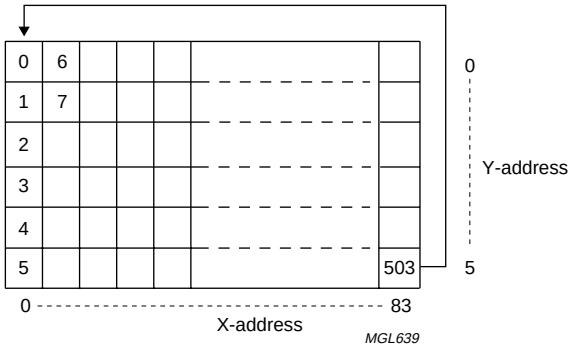


Fig.5 Sequence of writing data bytes into RAM with vertical addressing (V = 1).

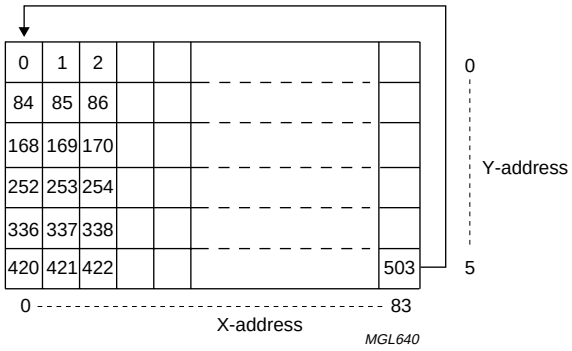
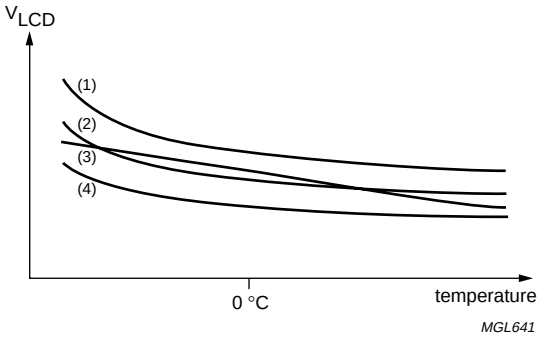


Fig.6 Sequence of writing data bytes into RAM with horizontal addressing (V = 0).

7.8 Temperature compensation

Due to the temperature dependency of the liquid crystals' viscosity, the LCD controlling voltage V_{LCD} must be increased at lower temperatures to maintain optimum contrast. Figure 7 shows V_{LCD} for high multiplex rates. In the PCD8544, the temperature coefficient of V_{LCD}, can be selected from four values (see Table 2) by setting bits TC_1 and TC_0.



(1) Upper limit.
(2) Typical curve.
(3) Temperature coefficient of IC.
(4) Lower limit.

Fig.7 V_{LCD} as function of liquid crystal temperature (typical values).

8 INSTRUCTIONS

The instruction format is divided into two modes: If D/$\overline{C}$ (mode select) is set LOW, the current byte is interpreted as command byte (see Table 1). Figure 8 shows an example of a serial data stream for initializing the chip. If D/$\overline{C}$ is set HIGH, the following bytes are stored in the display data RAM. After every data byte, the address counter is incremented automatically.

The level of the D/$\overline{C}$ signal is read during the last bit of data byte.

Each instruction can be sent in any order to the PCD8544. The MSB of a byte is transmitted first. Figure 9 shows one possible command stream, used to set up the LCD driver.

The serial interface is initialized when $\overline{SCE}$ is HIGH. In this state, SCLK clock pulses have no effect and no power is consumed by the serial interface. A negative edge on $\overline{SCE}$ enables the serial interface and indicates the start of a data transmission.

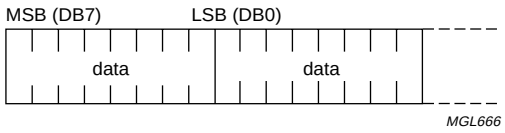


Fig.8 General format of data stream.

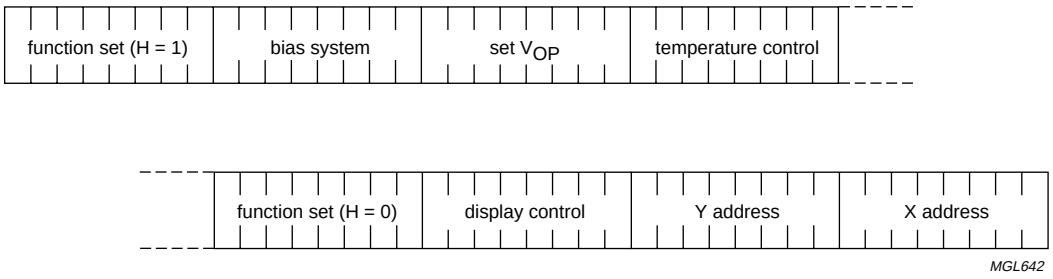


Fig.9 Serial data stream, example.

Figures 10 and 11 show the serial bus protocol.

- When $\overline{SCE}$ is HIGH, SCLK clock signals are ignored; during the HIGH time of $\overline{SCE}$, the serial interface is initialized (see Fig.12)
- SDIN is sampled at the positive edge of SCLK
- D/$\overline{C}$ indicates whether the byte is a command (D/$\overline{C}$ = 0) or RAM data (D/$\overline{C}$ = 1); it is read with the eighth SCLK pulse
- If $\overline{SCE}$ stays LOW after the last bit of a command/data byte, the serial interface expects bit 7 of the next byte at the next positive edge of SCLK (see Fig.12)
- A reset pulse with $\overline{RES}$ interrupts the transmission. No data is written into the RAM. The registers are cleared. If $\overline{SCE}$ is LOW after the positive edge of $\overline{RES}$, the serial interface is ready to receive bit 7 of a command/data byte (see Fig.13).

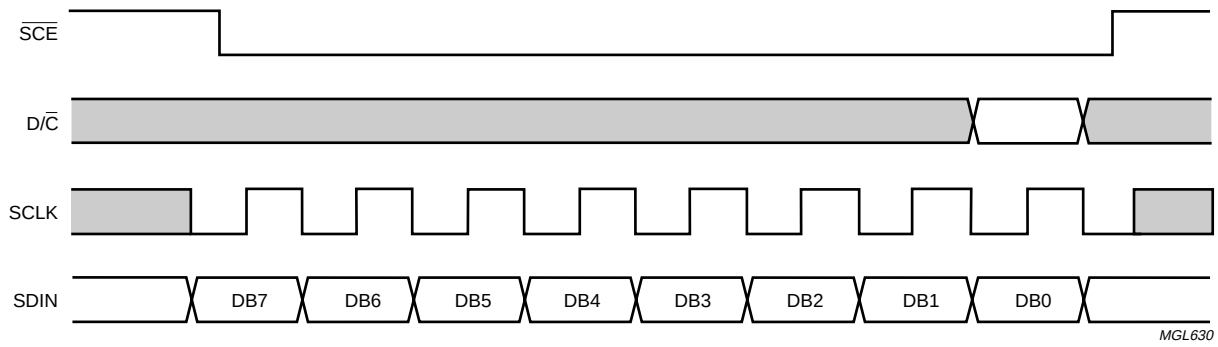


Fig.10 Serial bus protocol - transmission of one byte.

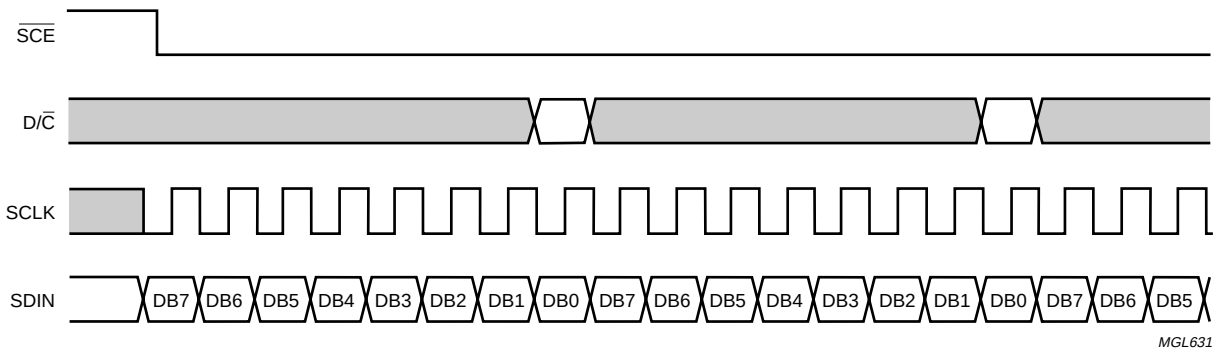


Fig.11 Serial bus protocol - transmission of several bytes.

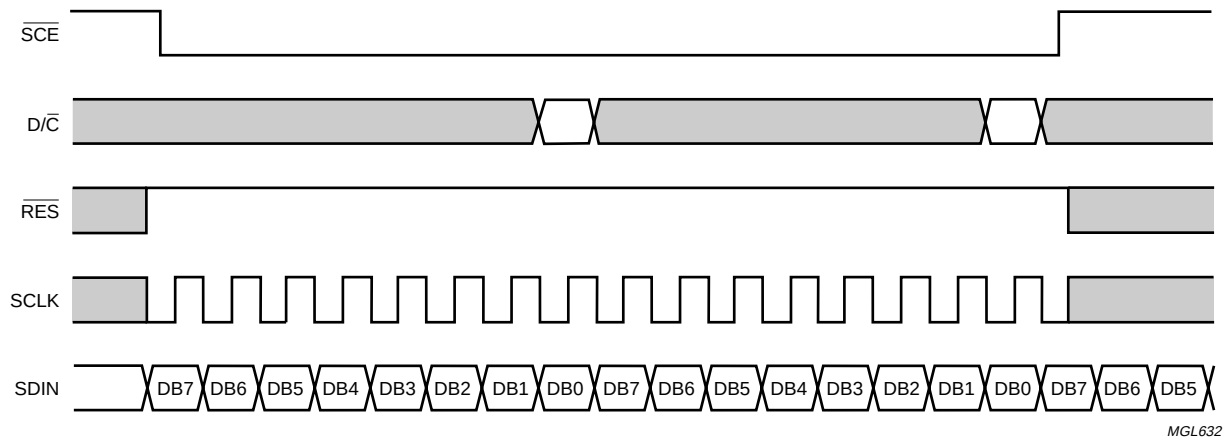


Fig.12 Serial bus reset function ($\overline{SCE}$).

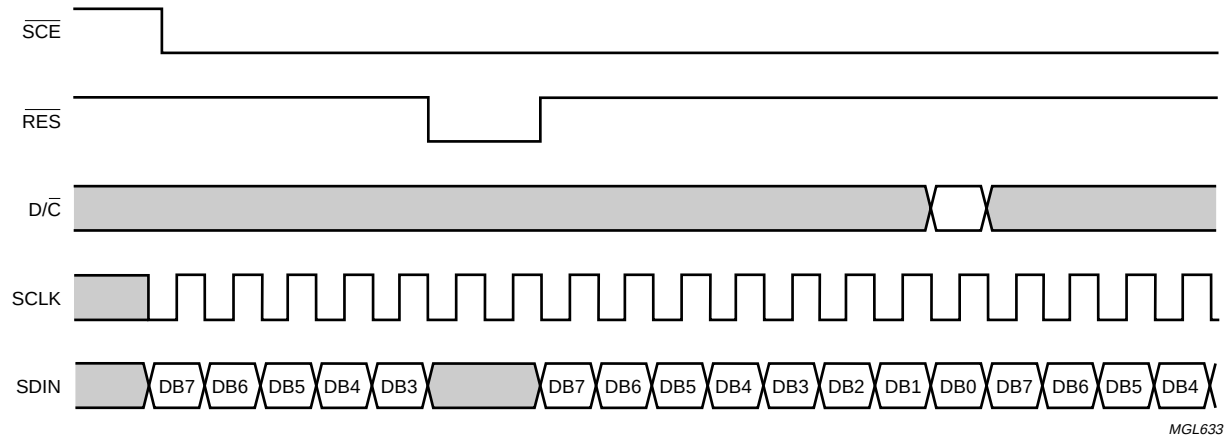


Fig.13 Serial bus reset function ($\overline{RES}$).

Table 1 Instruction set

INSTRUCTION	D/$\overline{C}$	COMMAND BYTE								DESCRIPTION
		DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0	
(H = 0 or 1)										
NOP	0	0	0	0	0	0	0	0	0	no operation
Function set	0	0	0	1	0	0	PD	V	H	power down control; entry mode; extended instruction set control (H)
Write data	1	D_7	D_6	D_5	D_4	D_3	D_2	D_1	D_0	writes data to display RAM
(H = 0)										
Reserved	0	0	0	0	0	0	1	X	X	do not use
Display control	0	0	0	0	0	1	D	0	E	sets display configuration
Reserved	0	0	0	0	1	X	X	X	X	do not use
Set Y address of RAM	0	0	1	0	0	0	Y_2	Y_1	Y_0	sets Y-address of RAM; $0 \leq Y \leq 5$
Set X address of RAM	0	1	X_6	X_5	X_4	X_3	X_2	X_1	X_0	sets X-address part of RAM; $0 \leq X \leq 83$
(H = 1)										
Reserved	0	0	0	0	0	0	0	0	1	do not use
	0	0	0	0	0	0	0	1	X	do not use
Temperature control	0	0	0	0	0	0	1	TC_1	TC_0	set Temperature Coefficient (TC_x)
Reserved	0	0	0	0	0	1	X	X	X	do not use
Bias system	0	0	0	0	1	0	BS_2	BS_1	BS_0	set Bias System (BS_x)
Reserved	0	0	1	X	X	X	X	X	X	do not use
Set V_{OP}	0	1	V_{OP6}	V_{OP5}	V_{OP4}	V_{OP3}	V_{OP2}	V_{OP1}	V_{OP0}	write V_{OP} to register

Table 2 Explanations of symbols in Table 1

BIT	0	1
PD	chip is active	chip is in Power-down mode
V	horizontal addressing	vertical addressing
H	use basic instruction set	use extended instruction set
D and E		
00	display blank	
10	normal mode	
01	all display segments on	
11	inverse video mode	
TC_1 and TC_0		
00	V_{LCD} temperature coefficient 0	
01	V_{LCD} temperature coefficient 1	
10	V_{LCD} temperature coefficient 2	
11	V_{LCD} temperature coefficient 3	

8.1 Initialization

Immediately following power-on, the contents of all internal registers and of the RAM are undefined. **A $\overline{\text{RES}}$ pulse must be applied**. Attention should be paid to the possibility that the **device may be damaged** if not properly reset.

All internal registers are reset by applying an external $\overline{\text{RES}}$ pulse (active LOW) at pad 31, within the specified time. However, the RAM contents are still undefined. The state after reset is described in Section 8.2.

The $\overline{\text{RES}}$ input must be $\leq 0.3V_{DD}$ when V_{DD} reaches V_{DDmin} (or higher) within a maximum time of 100 ms after V_{DD} goes HIGH (see Fig.16).

8.2 Reset function

After reset, the LCD driver has the following state:

- Power-down mode (bit PD = 1)
- Horizontal addressing (bit V = 0) normal instruction set (bit H = 0)
- Display blank (bit E = D = 0)
- Address counter X_6 to X_0 = 0; Y_2 to Y_0 = 0
- Temperature control mode (TC_1 TC_0 = 0)
- Bias system (BS_2 to BS_0 = 0)
- V_{LCD} is equal to 0, the HV generator is switched off (V_{OP6} to V_{OP0} = 0)
- After power-on, the RAM contents are undefined.

8.3 Function set

8.3.1 BIT PD

- All LCD outputs at V_{SS} (display off)
- Bias generator and V_{LCD} generator off, V_{LCD} can be disconnected
- Oscillator off (external clock possible)
- Serial bus, command, etc. function
- Before entering Power-down mode, the RAM needs to be filled with ‘0’s to ensure the specified current consumption.

8.3.2 BIT V

When V = 0, the horizontal addressing is selected. The data is written into the DDRAM as shown in Fig.6. When V = 1, the vertical addressing is selected. The data is written into the DDRAM, as shown in Fig.5.

8.3.3 BIT H

When H = 0 the commands ‘display control’, ‘set Y address’ and ‘set X address’ can be performed; when H = 1, the others can be executed. The ‘write data’ and ‘function set’ commands can be executed in both cases.

8.4 Display control

8.4.1 BITS D AND E

Bits D and E select the display mode (see Table 2).

8.5 Set Y address of RAM

Y_n defines the Y vector addressing of the display RAM.

Table 3 Y vector addressing

Y_2	Y_1	Y_0	BANK
0	0	0	0
0	0	1	1
0	1	0	2
0	1	1	3
1	0	0	4
1	0	1	5

8.6 Set X address of RAM

The X address points to the columns. The range of X is 0 to 83 (53H).

8.7 Temperature control

The temperature coefficient of V_{LCD} is selected by bits TC_1 and TC_0.

8.8 Bias value

The bias voltage levels are set in the ratio of R - R - nR - R - R, giving a 1/(n + 4) bias system. Different multiplex rates require different factors n (see Table 4). This is programmed by BS_2 to BS_0. For Mux 1 : 48, the optimum bias value n, resulting in 1/8 bias, is given by:

$$n = \sqrt{48} - 3 = 3.928 = 4 \quad (1)$$

Table 4 Programming the required bias system

BS_2	BS_1	BS_0	n	RECOMMENDED MUX RATE
0	0	0	7	1 : 100
0	0	1	6	1 : 80
0	1	0	5	1 : 65/1 : 65
0	1	1	4	1 : 48
1	0	0	3	1 : 40/1 : 34
1	0	1	2	1 : 24
1	1	0	1	1 : 18/1 : 16
1	1	1	0	1 : 10/1 : 9/1 : 8

Table 5 LCD bias voltage

SYMBOL	BIAS VOLTAGES	BIAS VOLTAGE FOR 1/8 BIAS
V1	V_{LCD}	V_{LCD}
V2	(n + 3)/(n + 4)	$^7/_8 \times V_{LCD}$
V3	(n + 2)/(n + 4)	$^6/_8 \times V_{LCD}$
V4	2/(n + 4)	$^2/_8 \times V_{LCD}$
V5	1/(n + 4)	$^1/_8 \times V_{LCD}$
V6	V_{SS}	V_{SS}

8.9 Set V_{OP} value

The operation voltage V_{LCD} can be set by software. The values are dependent on the liquid crystal selected. V_{LCD} = a + (V_{OP6} to V_{OP0}) × b [V]. In the PCD8544, a = 3.06 and b = 0.06 giving a program range of 3.00 to 10.68 at room temperature.

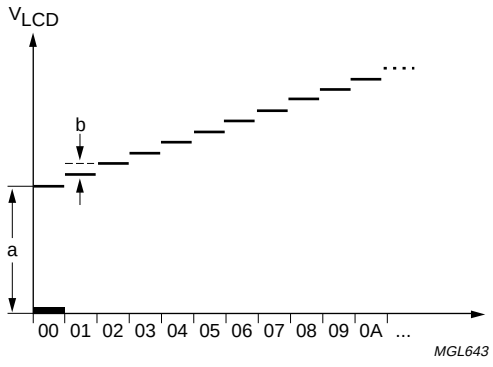
Note that the charge pump is turned off if V_{OP6} to V_{OP0} is set to zero.

For Mux 1 : 48, the optimum operation voltage of the liquid can be calculated as:

$$V_{LCD} = \frac{1 + \sqrt{48}}{\sqrt{2 \cdot \left(1 - \frac{1}{\sqrt{48}}\right)}} \cdot V_{th} = 6.06 \cdot V_{th} \qquad (2)$$

where V_{th} is the threshold voltage of the liquid crystal material used.

Caution, as V_{OP} increases with lower temperatures, care must be taken not to set a V_{OP} that will exceed the maximum of 8.5 V when operating at −25 °C.



a = 3.06.
b = 0.06.
V_{OP6} to V_{OP0} (programmed) [00 to 7FH].

Fig.14 V_{OP} programming.

9 LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134); see notes 1 and 2.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{DD}	supply voltage	note 3	–0.5	+7	V
V_{LCD}	supply voltage LCD	note 4	–0.5	+10	V
V_i	all input voltages		–0.5	V_{DD} + 0.5	V
I_{SS}	ground supply current		–50	+50	mA
I_I, I_O	DC input or output current		–10	+10	mA
P_{tot}	total power dissipation		–	300	mW
P_O	power dissipation per output		–	30	mW
T_{amb}	operating ambient temperature		–25	+70	°C
T_j	operating junction temperature		–65	+150	°C
T_{stg}	storage temperature		–65	+150	°C

Notes

1. Stresses above those listed under limiting values may cause permanent damage to the device.
2. Parameters are valid over operating temperature range unless otherwise specified. All voltages are with respect to V_{SS} unless otherwise noted.
3. With external LCD supply voltage externally supplied (voltage generator disabled). V_{DDmax} = 5 V if LCD supply voltage is internally generated (voltage generator enabled).
4. When setting V_{LCD} by software, take care not to set a V_{OP} that will exceed the maximum of 8.5 V when operating at –25 °C, see Caution in Section 8.9.

10 HANDLING

Inputs and outputs are protected against electrostatic discharge in normal handling. However, to be totally safe, it is desirable to take normal precautions appropriate to handling MOS devices (see *“Handling MOS devices”*).

11 DC CHARACTERISTICS

V_{DD} = 2.7 to 3.3 V; V_{SS} = 0 V; V_{LCD} = 6.0 to 9.0 V; T_{amb} = −25 to +70 °C; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{DD1}	supply voltage 1	LCD voltage externally supplied (voltage generator disabled)	2.7	–	3.3	V
V_{DD2}	supply voltage 2	LCD voltage internally generated (voltage generator enabled)	2.7	–	3.3	V
V_{LCD1}	LCD supply voltage	LCD voltage externally supplied (voltage generator disabled)	6.0	–	9.0	V
V_{LCD2}	LCD supply voltage	LCD voltage internally generated (voltage generator enabled); note 1	6.0	–	8.5	V
I_{DD1}	supply current 1 (normal mode) for internal V_{LCD}	V_{DD} = 2.85 V; V_{LCD} = 7.0 V; f_{SCLK} = 0; T_{amb} = 25 °C; display load = 10 μA; note 2	–	240	300	μA
I_{DD2}	supply current 2 (normal mode) for internal V_{LCD}	V_{DD} = 2.70 V; V_{LCD} = 7.0 V; f_{SCLK} = 0; T_{amb} = 25 °C; display load = 10 μA; note 2	–	–	320	μA
I_{DD3}	supply current 3 (Power-down mode)	with internal or external LCD supply voltage; note 3	–	1.5	–	μA
I_{DD4}	supply current external V_{LCD}	V_{DD} = 2.85 V; V_{LCD} = 9.0 V; f_{SCLK} = 0; notes 2 and 4	–	25	–	μA
I_{LCD}	supply current external V_{LCD}	V_{DD} = 2.7 V; V_{LCD} = 7.0 V; f_{SCLK} = 0; T = 25 °C; display load = 10 μA; notes 2 and 4	–	42	–	μA
Logic						
V_{IL}	LOW level input voltage		V_{SS}	–	$0.3V_{DD}$	V
V_{IH}	HIGH level input voltage		$0.7V_{DD}$	–	V_{DD}	V
I_L	leakage current	V_I = V_{DD} or V_{SS}	–1	–	+1	μA
Column and row outputs						
$R_{o(C)}$	column output resistance C0 to C83		–	12	20	kΩ
$R_{o(R)}$	row output resistance R0 to R47		–	12	20	kΩ
$V_{bias(tol)}$	bias voltage tolerance on C0 to C83 and R0 to R47		–100	0	+100	mV

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
LCD supply voltage generator						
V_{LCD}	V_{LCD} tolerance internally generated	V_{DD} = 2.85 V; V_{LCD} = 7.0 V; f_{SCLK} = 0; display load = 10 μA; note 5	–	0	300	mV
TC0	V_{LCD} temperature coefficient 0	V_{DD} = 2.85 V; V_{LCD} = 7.0 V; f_{SCLK} = 0; display load = 10 μA	–	1	–	mV/K
TC1	V_{LCD} temperature coefficient 1	V_{DD} = 2.85 V; V_{LCD} = 7.0 V; f_{SCLK} = 0; display load = 10 μA	–	9	–	mV/K
TC2	V_{LCD} temperature coefficient 2	V_{DD} = 2.85 V; V_{LCD} = 7.0 V; f_{SCLK} = 0; display load = 10 μA	–	17	–	mV/K
TC3	V_{LCD} temperature coefficient 3	V_{DD} = 2.85 V; V_{LCD} = 7.0 V; f_{SCLK} = 0; display load = 10 μA	–	24	–	mV/K

Notes

1. The maximum possible V_{LCD} voltage that may be generated is dependent on voltage, temperature and (display) load.
2. Internal clock.
3. RAM contents equal ‘0’. During power-down, all static currents are switched off.
4. If external V_{LCD}, the display load current is not transmitted to I_{DD}.
5. Tolerance depends on the temperature (typically zero at 27 °C, maximum tolerance values are measured at the temperate range limit).

12 AC CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
f_{OSC}	oscillator frequency		20	34	65	kHz
$f_{clk(ext)}$	external clock frequency		10	32	100	kHz
f_{frame}	frame frequency	f_{OSC} or $f_{clk(ext)}$ = 32 kHz; note 1	–	67	–	Hz
t_{VHRL}	V_{DD} to $\overline{RES}$ LOW	Fig.16	0[2]	–	30	ms
$t_{WL(RES)}$	$\overline{RES}$ LOW pulse width	Fig.16	100	–	–	ns
Serial bus timing characteristics						
f_{SCLK}	clock frequency	V_{DD} = 3.0 V ±10%	0	–	4.00	MHz
T_{cy}	clock cycle SCLK	All signal timing is based on 20% to 80% of V_{DD} and maximum rise and fall times of 10 ns	250	–	–	ns
t_{WH1}	SCLK pulse width HIGH		100	–	–	ns
t_{WL1}	SCLK pulse width LOW		100	–	–	ns
t_{su2}	$\overline{SCE}$ set-up time		60	–	–	ns
t_{h2}	$\overline{SCE}$ hold time		100	–	–	ns
t_{WH2}	$\overline{SCE}$ min. HIGH time		100	–	–	ns
t_{h5}	$\overline{SCE}$ start hold time; note 3		100	–	–	ns
t_{su3}	D/$\overline{C}$ set-up time		100	–	–	ns
t_{h3}	D/$\overline{C}$ hold time		100	–	–	ns
t_{su4}	SDIN set-up time		100	–	–	ns
t_{h4}	SDIN hold time		100	–	–	ns

Notes

1. $T_{frame} = \frac{f_{clk(ext)}}{480}$
2. $\overline{RES}$ may be LOW before V_{DD} goes HIGH.
3. t_{h5} is the time from the previous SCLK positive edge (irrespective of the state of $\overline{SCE}$) to the negative edge of $\overline{SCE}$ (see Fig.15).

12.1 Serial interface

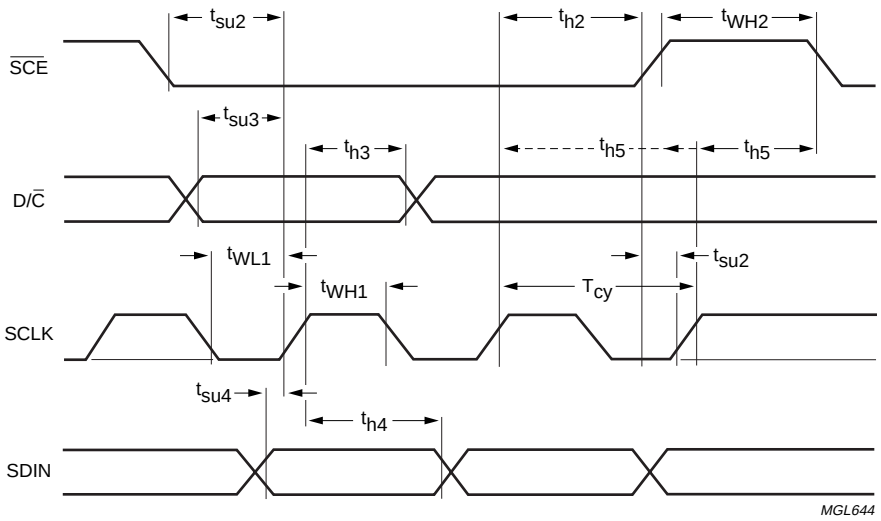


Fig.15 Serial interface timing.

12.2 Reset

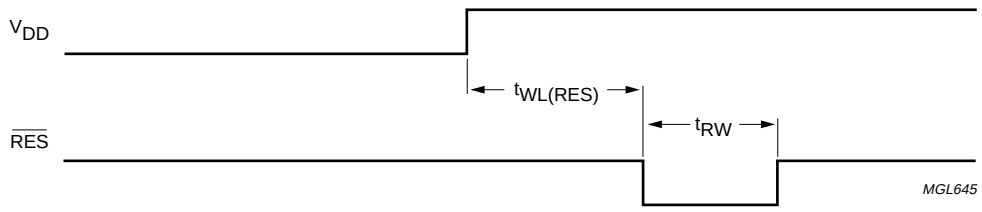
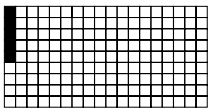
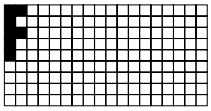
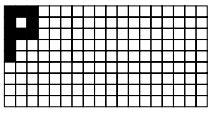
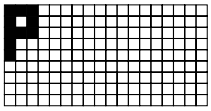
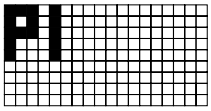
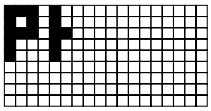
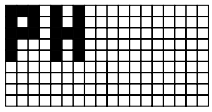
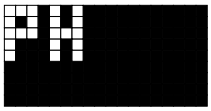
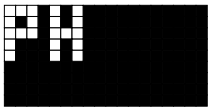
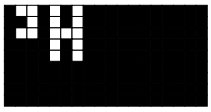


Fig.16 Reset timing.

13 APPLICATION INFORMATION

Table 6 Programming example

STEP	SERIAL BUS BYTE									DISPLAY	OPERATION
	D/$\overline{C}$	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0		
1	start										$\overline{SCE}$ is going LOW
2	0	0	0	1	0	0	0	0	1		function set PD = 0 and V = 0, select extended instruction set (H = 1 mode)
3	0	1	0	0	1	0	0	0	0		set V_{OP}; V_{OP} is set to a +16 × b [V]
4	0	0	0	1	0	0	0	0	0		function set PD = 0 and V = 0, select normal instruction set (H = 0 mode)
5	0	0	0	0	0	1	1	0	0		display control set normal mode (D = 1 and E = 0)
6	1	0	0	0	1	1	1	1	1	 MGL673	data write Y and X are initialized to 0 by default, so they are not set here
7	1	0	0	0	0	0	1	0	1	 MGL674	data write
8	1	0	0	0	0	0	1	1	1	 MGL675	data write
9	1	0	0	0	0	0	0	0	0	 MGL675	data write
10	1	0	0	0	1	1	1	1	1	 MGL676	data write

STEP	SERIAL BUS BYTE									DISPLAY	OPERATION
	D/$\overline{C}$	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0		
11	1	0	0	0	0	0	1	0	0	 MGL677	data write
12	1	0	0	0	1	1	1	1	1	 MGL678	data write
13	0	0	0	0	0	1	1	0	1	 MGL679	display control; set inverse video mode (D = 1 and E = 1)
14	0	1	0	0	0	0	0	0	0	 MGL679	set X address of RAM; set address to ‘0000000’
15	1	0	0	0	0	0	0	0	0	 MGL680	data write

The pinning is optimized for single plane wiring e.g. for chip-on-glass display modules. Display size: 48 × 84 pixels.

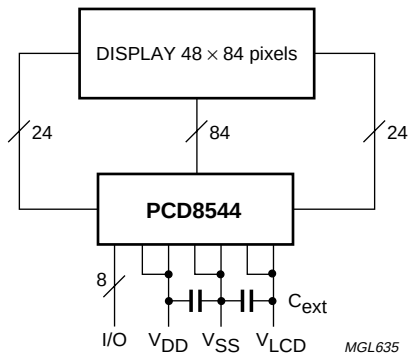


Fig.17 Application diagram.

The required minimum value for the external capacitors is: C_{ext} = 1.0 μF.

Higher capacitor values are recommended for ripple reduction.

14 BONDING PAD LOCATIONS

14.1 Bonding pad information (see Fig.18)

PARAMETER	SIZE
Pad pitch	min. 100 μm
Pad size, aluminium	80 × 100 μm
Bump dimensions	59 × 89 × 17.5 (±5) μm
Wafer thickness	max. 380 μm

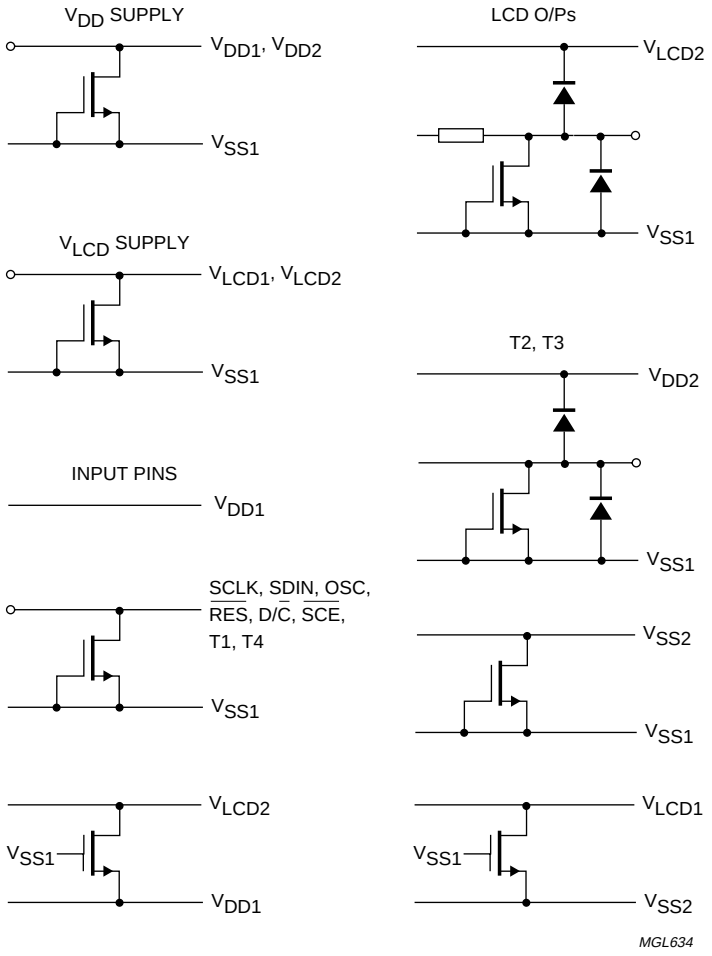


Fig.19 Device protection diagram.